Lecture4

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Source-free case

- Once again, the "source-free" Poisson equation is the Laplace equation.
 - Since we are (incorrectly) calling the $\nabla \cdot \mathbf{D} = \rho(\mathbf{r})$ as the Poisson equation, the source-free case (no net charge, $\rho(\mathbf{r}) = 0$) is not reduced to the Laplace equation.
 - Instead, (under the electrostatic approximation)

$$\nabla \cdot [\epsilon(\mathbf{r}) \nabla \phi(\mathbf{r})] = 0$$

In the 1D strcture,

$$\frac{d}{dx} \left[\epsilon(x) \frac{d}{dx} \phi(x) \right] = 0$$

Comparison

Laplace equation

$$\frac{d}{dx} \left[\frac{d}{dx} \phi(x) \right] = 0$$

(Generalized) Poisson equation with the source-free condition

$$\frac{d}{dx} \left[\epsilon(x) \frac{d}{dx} \phi(x) \right] = 0$$

They look quite similar. However, they are not.

Two capacitors

- Capacitor made of a single dielectric layer
 - Its thickness is 5 nm. Its relative permittivity is 11.7.
- Capacitor made of two dielectric layers
 - Each of them is 2.5 nm thick. Their relative permittivity is 11.7 and 3.9, respectively.

$$x = 0 x = a x = 0 x = 0.5a x = a$$

$$\phi(0) = 0 V \epsilon = 11.7 \epsilon_0 = 1 V = 0 V = 11.7 \epsilon_0 = 3.9 \epsilon_0 = 1 V$$

$$\phi(x) = \frac{x}{a} \qquad \qquad \phi(x) = \frac{3x}{2a} - \frac{1}{2}$$

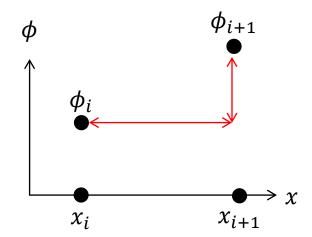
Discretization

- How to treat the position-dependent permittivity
 - For $2 \le i \le N-1$, the integration from $x_{i-0.5}$ to $x_{i+0.5}$ yields

$$\epsilon(x_{i+0.5}) \frac{d\phi}{dx} \bigg|_{x_{i+0.5}} - \epsilon(x_{i-0.5}) \frac{d\phi}{dx} \bigg|_{x_{i-0.5}} = 0$$

The first derivative is approximated by

$$\left. \frac{d\phi}{dx} \right|_{x_{i+0.5}} \approx \frac{\phi_{i+1} - \phi_i}{x_{i+1} - x_i}$$



N = 5 example

- At x_3 , two layers ($\epsilon_1 = 11.7 \epsilon_0$ and $\epsilon_2 = 3.9 \epsilon_0$) meet.
 - It is simply given by

$$Ax = \begin{bmatrix} 1 & 0 & 0 & 0 & 0 \\ \epsilon_1 & -2\epsilon_1 & \epsilon_1 & 0 & 0 \\ 0 & \epsilon_1 & -\epsilon_2 - \epsilon_1 & \epsilon_2 & 0 \\ 0 & 0 & \epsilon_2 & -2\epsilon_2 & \epsilon_2 \\ 0 & 0 & 0 & 0 & 1 \end{bmatrix} \begin{bmatrix} \phi(x_1) \\ \phi(x_2) \\ \phi(x_3) \\ \phi(x_4) \\ \phi(x_5) \end{bmatrix} = \begin{bmatrix} 0 \\ 0 \\ 0 \\ 1 \end{bmatrix} = b$$

- Note that the third row has different coefficients.
- When $\epsilon_1 = \epsilon_2$, it is reduced to the Laplace equation.

MATLAB example

Step-by-step procedure

First, set the matrix, A.

```
A = zeros(5,5);
A(1,1) = 1.0;
A(2,1) = 11.7; A(2,2) = -23.4; A(2,3) = 11.7;
A(3,2) = 11.7; A(3,3) = -15.6; A(3,4) = 3.9;
A(4,3) = 3.9; A(4,4) = -7.8; A(4,5) = 3.9;
A(5,5) = 1.0;
```

Next, set the vector, b.

$$b = zeros(5,1); b(5,1) = 1.0;$$

Finally, get the solution vector, x.

$$x = A \setminus b$$

Homework#4

- Due: AM08:00, September 16 (This Wednesday)
- Problem#1
 - Consider a heterostructure. It has two layers. Thickness of the SiO₂ layer is 0.5 nm. Its relative permittivity is 3.9. A 1.9 nm-thick HfO₂ layer is followed. Its relative permittivity is 22.0.
 - Ignore mobile carriers.
 - Then, calculate the capacitance per area. (F/cm²)
 - Compare your result with the analytic expression.